SPTECH Silicon NPN Power Transistor

BUX48A

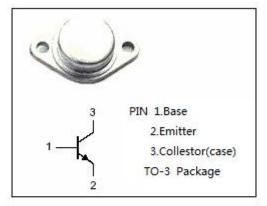
DESCRIPTION

- · High Voltage Capability
- · High Current Capability
- · Fast Switching Speed

APPLICATIONS

Designed for high-voltage, high-speed, power switching in inductive circuits where fall time is critical. They are particulary suited for line-operated swtchmode applications such as:

- Switching regulators
- Inverters
- Solenoid and relay drivers
- Motor controls
- · Deflection circuits

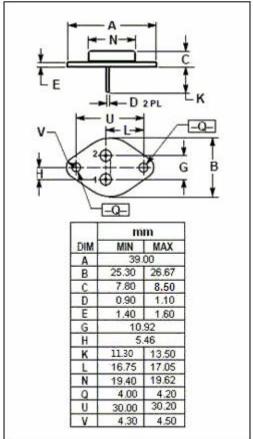


Absolute maximum ratings(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CEX}	Collector-Emitter Voltage (V _{BE} = -1.5V) 1000		V
V _{CEO}	Collector-Emitter Voltage	450	V
V _{EBO}	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	15	Α
I _{CM}	Collector Current-Peak	30	Α
lΒ	Base Current-Continuous	4	Α
I _{BM}	Base Current-peak	20	Α
Pc	Collector Power Dissipation @T _C =25℃	175	W
T _j	Junction Temperature	200	$^{\circ}$
T _{stg}	Storage Temperature Range	-65~200	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	MBOL PARAMETER		UNIT
R _{th j-c}	R _{th j-c} Thermal Resistance,Junction to Case		°C/W



1

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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT	
$V_{\text{CEO(SUS)}}$	Collector-Emitter Sustaining Voltage	I _C = 20mA ; I _B = 0	450		V	
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I _E = 50mA; I _C = 0	7		V	
V _{CE} (sat)-1	Collector-Emitter Saturation Voltage	I _C = 8A; I _B = 1.6A I _C = 8A; I _B = 1.6A;T _C = 100℃		1.5 2.0	V	
V _{CE(sat)-2}	Collector-Emitter Saturation Voltage	I _C = 12A ;I _B = 2.4A		5.0	٧	
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 8A; I _B = 1.6A I _C = 8A; I _B = 1.6A;T _C = 100℃		1.6 1.6	٧	
Ісво	Collector Cutoff Current	V _{CE} =1000V; I _E = 0 V _{CE} =100V; I _E = 0;T _C =125°C		0.2 2	mA	
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0		0.1	mA	
h _{FE}	DC Current Gain	I _C = 8A ; V _{CE} = 5V	8			
Сов	Output Capacitance	I _E = 0 ; V _{CB} = 10V,f _{test} = 1MHz		350	pF	

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